

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



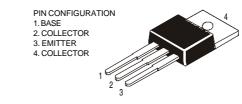


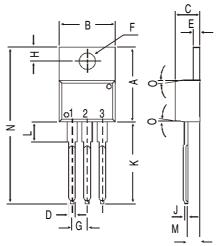
TO-220 Plastic Package

2N6109

2N6109 PNP PLASTIC POWER TRANSISTOR

General Purpose Amplifier and Switching Application





diminsions in mm.	DIM	MIN.	MAX.
	Α	14.42	16.51
	В	9.63	10.67
	С	3.56	4.83
	D		0.90
	Е	1.15	1.40
	F	3.75	3.88
	G	2.29	2.79
	Н	2.54	3.43
	J		0.56
	K	12.70	14.73
	L	2.80	4.07
	М	2.03	2.92
	N		31.24
₹	0	DEG 7	

ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)	V_{CBO}	max.	60 V
Collector-emitter voltage (open base)	V_{CEO}	max.	50 V
Collector current	I_C	max.	7.0 A
Total power dissipation up to $T_C = 25^{\circ}C$	P_{tot}	max.	40 W
Junction temperature	T_{j}	max.	150 ℃
Collector-emitter saturation voltage	,		
$I_C = 2.5A$; $I_B = 0.25A$	V_{CEsat}	max.	1.0 V
D.C. current gain			
$I_C = 2.5A; V_{CE} = 4V$	h_{FE}	min.	30
		max.	150

RATINGS (at T_A =25°C unless otherwise specified) Limiting values

Collector-base voltage (open emitter)	V_{CBO}	max.	60 V
Collector-emitter voltage (open base)	V_{CEO}	max.	50 V
Emitter-base voltage (open collector)	V_{EBO}	max.	5.0 V
Collector current	I_C	max.	7.0 A

Collector current (Peak value) Base current Total power dissipation up to $T_C = 25^{\circ}C$ Derate above $25^{\circ}C$ Junction temperature Storage temperature THERMAL CHARACTERISTICS From junction to case	I_{C} I_{B} P_{tot} T_{j} T_{stg} $R_{th \ j-c}$	max. max. max. max. max.	150 +150	$\begin{matrix} A \\ W \\ W/ {}^{}\!$
from function to cuse	in j-c		5.125	C/ //
CHARACTERISTICS				
$T_{amb} = 25^{\circ}C$ unless otherwise specified				
Collector cutoff current				
$I_B = 0$; $V_{CE} = 40V$	I_{CEO}	max.	1.0	mA
$V_{EB(off)} = 1.5V; V_{CE} = 60V$	I_{CEX}	max.		mA
$V_{EB(off)} = 1.5V; V_{CE} = 50V; T_C = 150$ °C	I_{CEX}	max.	2.0	mA
Emitter cut-off current				
$I_C = 0; \ V_{EB} = 5V$	I_{EBO}	max.	1.0	mA
Breakdown voltages				
$I_C = 100 \ mA; I_B = 0$	$V_{CEO(sus)}^*$	min.	50	V
$I_C = 1 mA; I_E = 0$	V_{CBO}	min.	60	V
$I_E = 1 mA; I_C = 0$	V_{EBO}	min.	5.0	V
Saturation voltages				
$I_C = 2.5 A$; $I_B = 0.25 A$	V_{CEsat}^*	max.	1.0	V
$I_C = 7 A$; $I_B = 3 A$	V_{CEsat}^*	max.	3.5	V
Base emitter on voltages				
$I_C = 2.5A; V_{CE} = 4V$	$V_{BE(on)}^*$	max.	1.5	V
$I_C = 7A$; $V_{CE} = 4V$	$V_{BE(on)}^*$	max.	3.0	V
D.C. current gain				
$I_C = 2.5A; V_{CE} = 4V$	h_{FE}^*	min.	30	
		max.	150	
$I_C = 7A$; $V_{CE} = 4V$	h_{FE}^*	min.	2.3	
Small-signal current gain $f = 50 KHz$	"FE	111111.	2.0	
$I_C = 0.5A; V_{CE} = 4V$	h_{fe}	min.	20	
Output capacitance at $f = 1$ MHz	rije	111111.	20	
$I_E = 0; V_{CB} = 10V$	C_o	max.	250	nЕ
Transition frequency at $f = 1$ MHz	c_0	mux.	250	<i>P</i> 1
$I_C = 500 \text{ mA}; V_{CE} = 4V$	f _T (1)	min.	10	MHz
10 - 300 mill, VCE - IV	J1 (±/	114414.	10	171114

^{*} Pulse test: pulse width \leq 300 µs; duty cycle \leq 2%. (1) $f_T = |h_{f\!e}| \cdot f_{test}$

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-2579 6150, 5141 1112 Fax + 91-11-2579 5290, 5141 1119 email@cdil.com www.cdilsemi.com